NSN 5962-01-226-2273

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high to low level

View Online at https://aerobasegroup.com/nsn/5962-01-226-2273

Body Length:	
0.840 inches	
Body Width:	
Between 0.220 in	ches and 0.310 inches
Body Height:	
0.185 inches	
Maximum Powe	Dissipation Rating:
739.0 milliwatts	
Operating Temp	urature Range:
-55.0/+125.0 deg	ees celsius
Storage Tempur	ature Range:
·65.0/+150.0 deg	ees celsius
End Application	
An/bps14to15e	
Features Provid	ed:
Hermetically seal	ed and burn in and bipolar and schottky and programmable and w/active pull-up
Inclosure Materi	al:
Ceramic	
Inclosure Config	uration:
Dual-in-line	
Output Logic Fo	m:
Transistor-transis	or logic
Input Circuit Pat	ern:
10 input	
Case Outline So	urce And Designator:
D-2 mil-m-38510	
Terminal Surfac	e Treatment:
Solder	
Voltage Rating A	nd Type Per Characteristic:
7.0 volts powers	ource
Time Rating Per	Chacteristic:
75.00 nanosecon	ds propagation delay time, low to high level output and 75.00 nanoseconds propagation delay time,
output	
Memory Device	Гуре:
Rom	
Memory Capacit	y:
Unknown	
Test Data Docur	nent:
96906-mil-std-88	standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type A	nd Quantity:
16 printed circuit	
Shelf Life:	
N/a	

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Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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